

The SG275□ photointerrupter high-performance standard type, combines high-output GaAs IRED with high sensitive phototransistor.

FEATURES

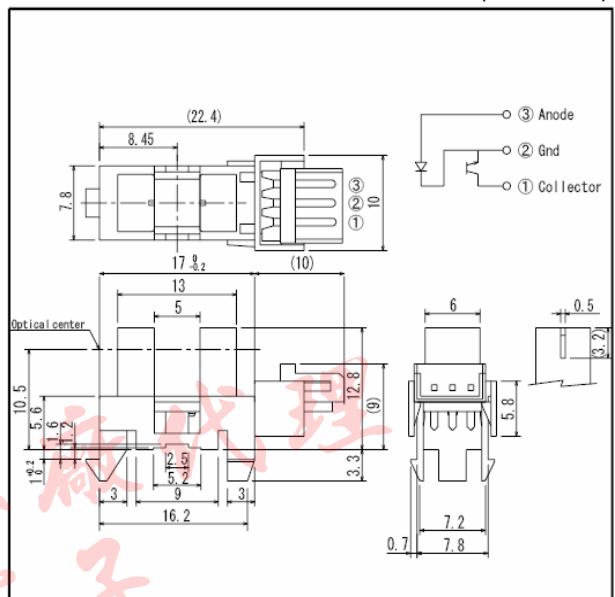
- Connector type AMP(JAPAN),Ltd.
- GAP : 5mm
- Snap-in mount
- 3 kinds of mounting plate thicknesses : 1.0mm, 1.2mm, 1.6mm

APPLICATIONS

- Copiers
- Printers
- ATM
- Ticket vending machines

DIMENSIONS

(Unit : mm)



MAXIMUM RATINGS

(Ta=25°C)

Item	Symbol	Rating	Unit
Input	P _D	100	mW
	I _F	60	mA
	V _R	5	V
	I _{FP}	1	A
Output	P _C	100	mW
	I _C	40	mA
	V _{CEO}	30	V
	V _{ECO}	5	V
Operating temp. ^{*2*3}	Topr.	-20 ~ +75	°C
Storage temp. ^{*2*3}	Tstg.	-30 ~ +85	°C

*1. Pulse width : tw≤100us. period T=10ms

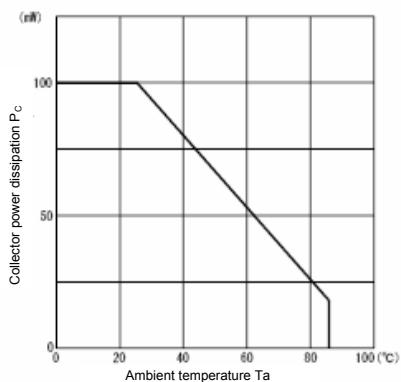
*2. No icebound or dew *3. The connector shall be inserted or pulled at normal temperature.

ELECTRO-OPTICAL CHARACTERISTICS

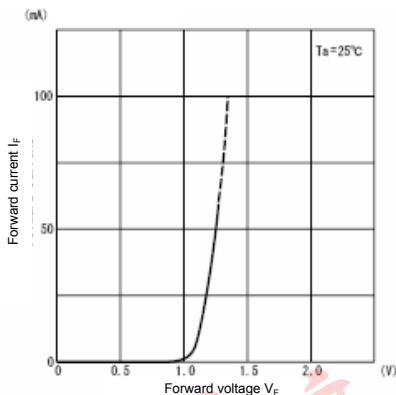
(Ta=25°C)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Input	V _F	I _F =20mA	-	1.2	1.4	V
	I _R	V _R =5V	-	-	10	μA
	λ _p	I _F =20mA	-	940	-	nm
Output	I _{CEO}	V _{CE} =10V,0 lx	-	1	100	nA
Trans-mission	I _C	I _F =20mA,V _{CE} =5V (Non-Shading)	0.6	-	10	mA
	I _{CEO}	I _F =20mA,V _{CE} =5V (Shading)	-	0.5	10	μA
	V _{CE(sat)}	I _F =20mA,I _C =0.1mA	-	0.15	0.4	V
Rise time		V _{CC} =5V,I _C =2mA,R _L =100Ω	-	4	-	μs
Fall time			-	5	-	μs

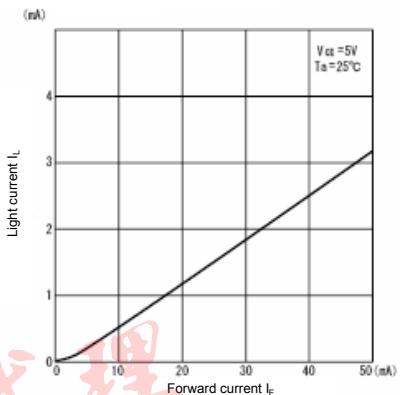
**Collector power dissipation Vs.
Ambient temperature**



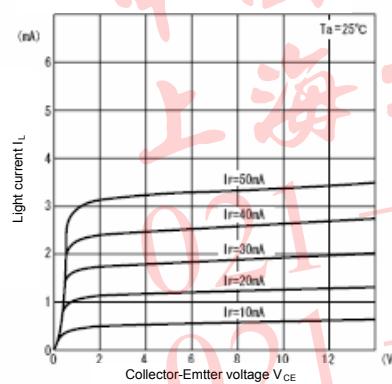
**Forward current Vs.
Forward voltage**



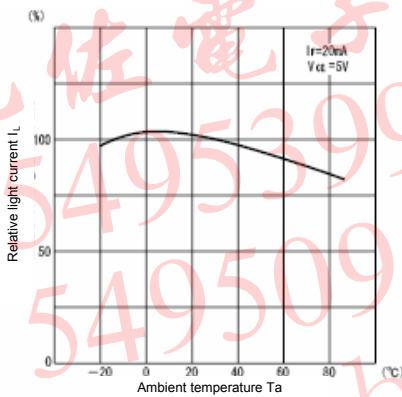
**Light current Vs.
Forward current**



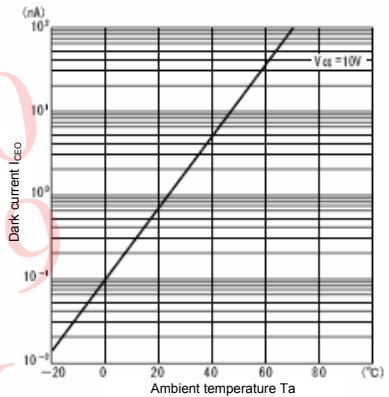
**Light current Vs.
Collector-Emitter voltage**



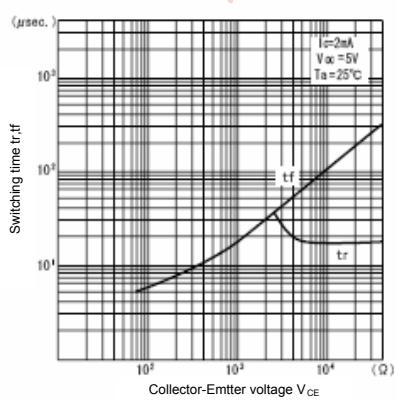
**Relative light current Vs.
Ambient temperature**



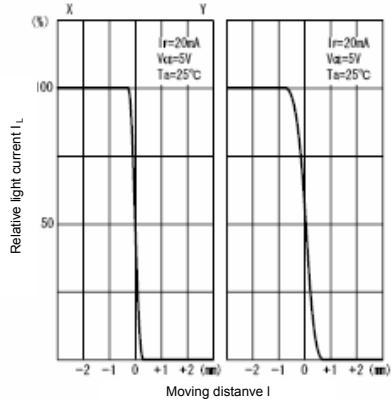
**Dark current Vs.
Ambient temperature**



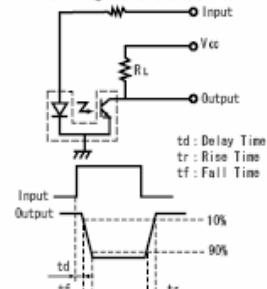
**Switching time Vs.
Load resistance *1**



**Relative light current Vs.
Moving distance *2**



*1 Switching time measurement circuit



*2 Method of measuring position detection characteristic

